

2MBI225XNA120-50

IGBT Modules

Power Module (X series)
1200V / 225A / 2-in-1 package

■ **Features**

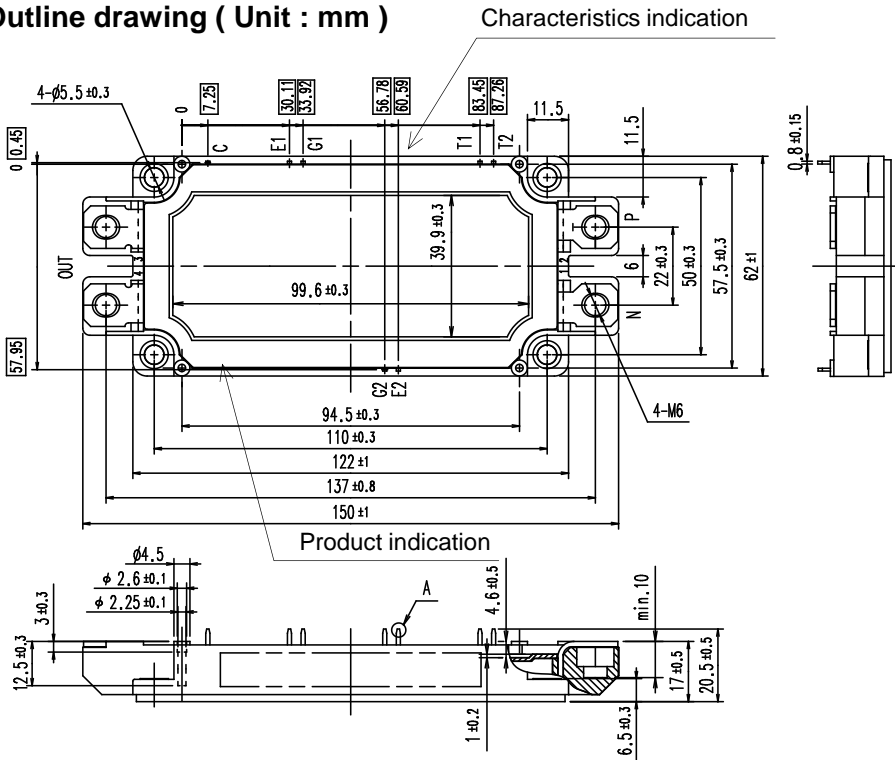
- Low $V_{CE(sat)}$
- Low Inductance Module structure
- Solder pin terminals

■ **Applications**

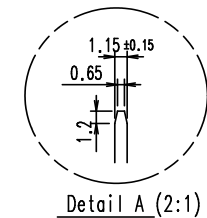
- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems



■ **Outline drawing (Unit : mm)**

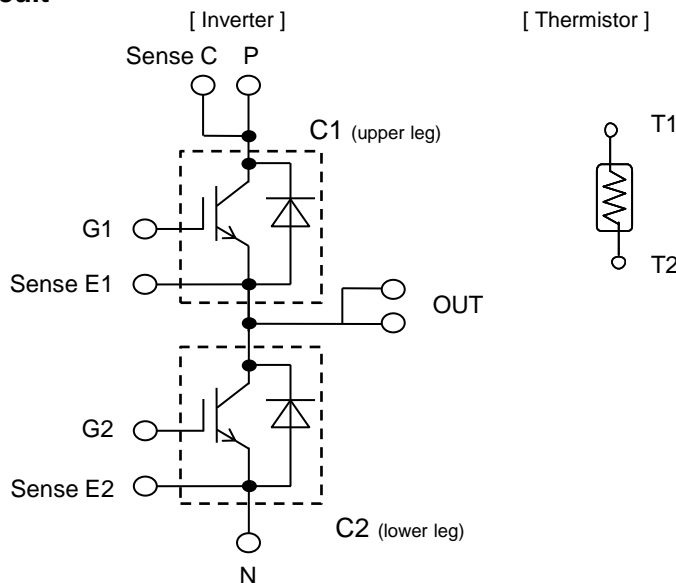


NOTE) shows theoretical dimension and tolerance is $\phi \pm 0.5$



Weight: 350 g(typ.)

■ **Equivalent Circuit**



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■ Absolute Maximum Ratings (at $T_C=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units
Inverter	Collector-emitter voltage, gate-emitter short-circuited	V_{CES}		1200	V
	Gate-emitter voltage, collector-emitter short-circuited	V_{GES}		± 20	V
	Collector current	I_C	Continuous $T_C=100^\circ\text{C}$	225	A
	Repetitive peak collector current	I_{CRM}	1ms	450	
	Forward current	I_F		225	
	Repetitive peak forward current	I_{FRM}	1ms	450	
	Total power dissipation	P_{tot}	1 device	1030	
	Virtual junction temperature	T_{vj}		175	°C
	Operating junction temperature (under switching conditions)	T_{vjop}		175	
	Case temperature	T_C		125	
Storage temperature	T_{stg}		-40 ~ 125		
Isolation voltage	between terminal and copper base (*1)	V_{isol}	AC: 1min.	2500	Vrms
	between thermistor and others (*2)				
Mounting torque of screws to heatsink (*3)		M_s	M5	6.0	N·m
Mounting torque of screws to terminals (*3)		M_t	M6	6.0	

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value: : Mounting torque of screws to heatsink 2.5 ~ 6.0 N·m (M5)
 Recommendable Value: : Mounting torque of screws to terminals 3.5 ~ 6.0 N·m (M6)

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Collector-emitter cut-off current, gate-emitter short-circuited	I_{CES}	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	150	μA	
Gate leakage current, collector-emitter short-circuited	I_{GES}	$V_{CE}=0\text{V}, V_{GE}=\pm 20\text{V}$	-	-	300	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 225\text{mA}$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 225\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.75	2.20	V
	$V_{CE(sat)}$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.45	1.90	
			$T_{vj}=125^{\circ}\text{C}$	-	1.80	-	
			$T_{vj}=150^{\circ}\text{C}$	-	1.90	-	
		$T_{vj}=175^{\circ}\text{C}$	-	1.95	-		
Internal gate resistance	r_g	-	-	5.00	-	Ω	
Capacitance	C_{ies}	$V_{CE}=10\text{V}, V_{GE}=0\text{V}, f=1\text{MHz}$	-	24	-	nF	
	C_{oes}		-	0.8	-		
	C_{res}		-	0.21	-		
Gate charge	Q_G	$V_{CC} = 600\text{V}, I_C = 225\text{A}$ $V_{GE} = -15 \rightarrow +15\text{V}$	-	1.6	-	μC	
Forward voltage	V_F (terminal)	$V_{GE} = 0\text{V}$ $I_F = 225\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.90	2.35	V
	V_F (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.60	2.05	
			$T_{vj}=125^{\circ}\text{C}$	-	1.65	-	
			$T_{vj}=150^{\circ}\text{C}$	-	1.60	-	
		$T_{vj}=175^{\circ}\text{C}$	-	1.60	-		
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 225\text{A}$ $V_{GE} = +15/-15\text{V}$ $R_G = \pm 0.82\Omega$ $L_S = 35\text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.23	-	μs
			$T_{vj}=125^{\circ}\text{C}$	-	0.27	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.27	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.28	-	
	t_r		$T_{vj}=25^{\circ}\text{C}$	-	0.07	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.08	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.08	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.08	-	
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	0.33	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.35	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.35	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.36	-	
t_f	$T_{vj}=25^{\circ}\text{C}$	-	0.05	-			
	$T_{vj}=125^{\circ}\text{C}$	-	0.06	-			
	$T_{vj}=150^{\circ}\text{C}$	-	0.07	-			
	$T_{vj}=175^{\circ}\text{C}$	-	0.08	-			
Reverse recovery time	t_{rr}	$T_{vj}=25^{\circ}\text{C}$	-	0.14	-		
		$T_{vj}=125^{\circ}\text{C}$	-	0.27	-		
		$T_{vj}=150^{\circ}\text{C}$	-	0.35	-		
		$T_{vj}=175^{\circ}\text{C}$	-	0.40	-		

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}= 25^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
					min.	typ.	max.	
Inverter	Switching loss (per pulse)	E_{on}	$V_{CC} = 600\text{V}$ $I_C, I_F = 225\text{A}$ $V_{GE} = +15/-15\text{V}$ $R_G = \pm 0.82\Omega$ $L_S = 35\text{nH}$	$T_{vj}=25^{\circ}\text{C}$	-	21.5	-	mJ
				$T_{vj}=125^{\circ}\text{C}$	-	31.4	-	
				$T_{vj}=150^{\circ}\text{C}$	-	35.1	-	
				$T_{vj}=175^{\circ}\text{C}$	-	38.6	-	
		E_{off}		$T_{vj}=25^{\circ}\text{C}$	-	14.3	-	
				$T_{vj}=125^{\circ}\text{C}$	-	17.9	-	
				$T_{vj}=150^{\circ}\text{C}$	-	18.8	-	
				$T_{vj}=175^{\circ}\text{C}$	-	20.6	-	
		E_{rr}		$T_{vj}=25^{\circ}\text{C}$	-	9.1	-	
				$T_{vj}=125^{\circ}\text{C}$	-	14.0	-	
				$T_{vj}=150^{\circ}\text{C}$	-	15.7	-	
				$T_{vj}=175^{\circ}\text{C}$	-	18.7	-	
Thermistor	Resistance	R	$T = 25^{\circ}\text{C}$	-	5000	-	Ω	
			$T = 100^{\circ}\text{C}$	465	495	520		
	B value	B	$T = 25/ 50^{\circ}\text{C}$	3305	3375	3450	K	

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

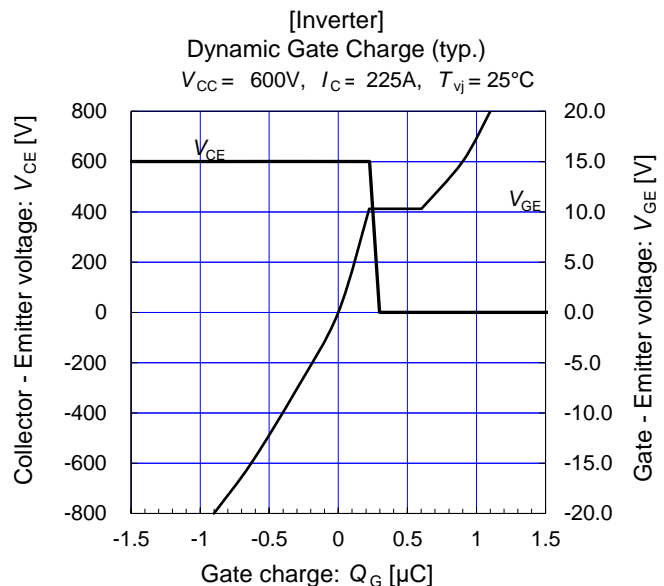
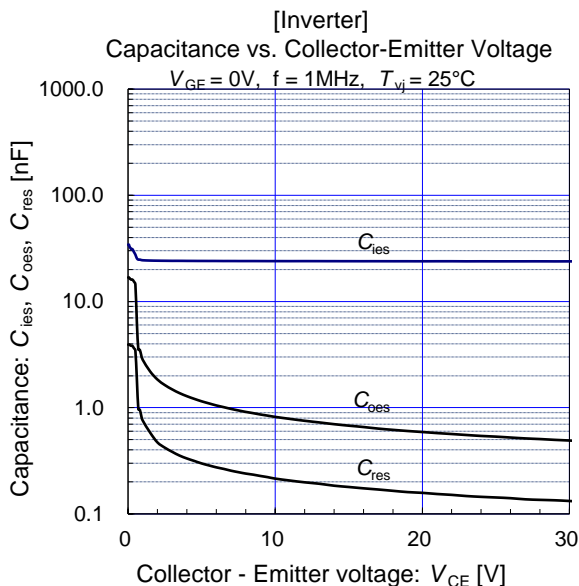
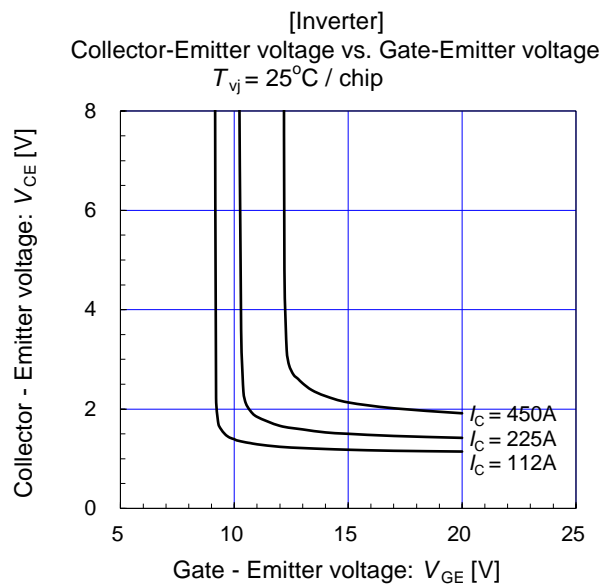
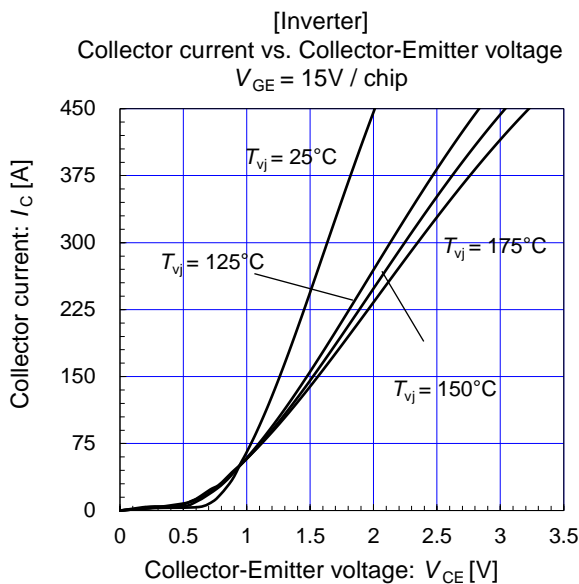
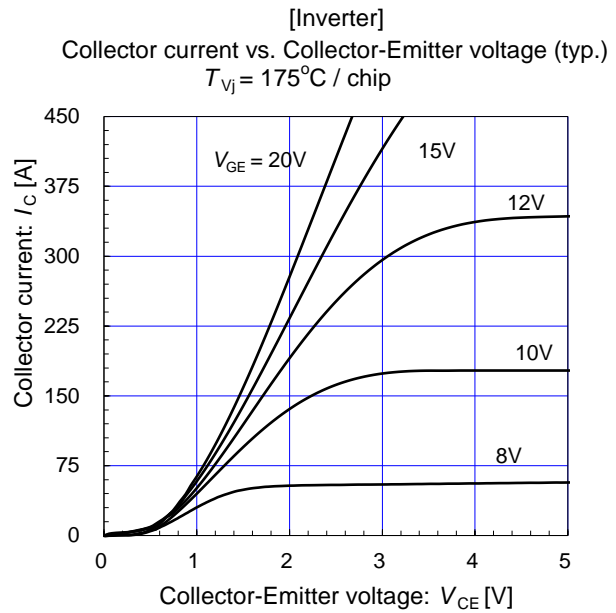
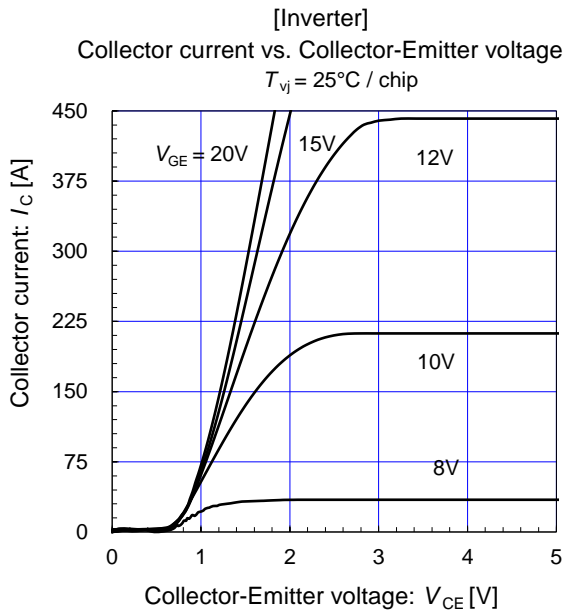
■ Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case(1 device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.145	$^{\circ}\text{C/W}$
		Inverter FWD	-	-	0.190	
Thermal resistance case to heatsink(1 IGBT+1 FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m $\cdot^{\circ}\text{C}$) thermal grease	-	0.0167	-	

(*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

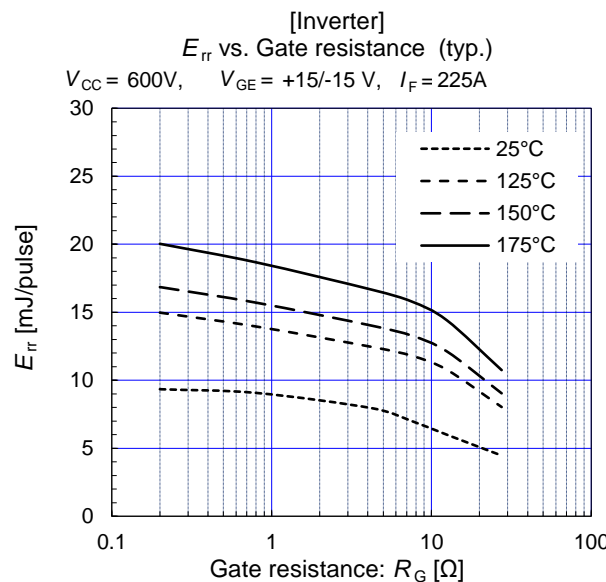
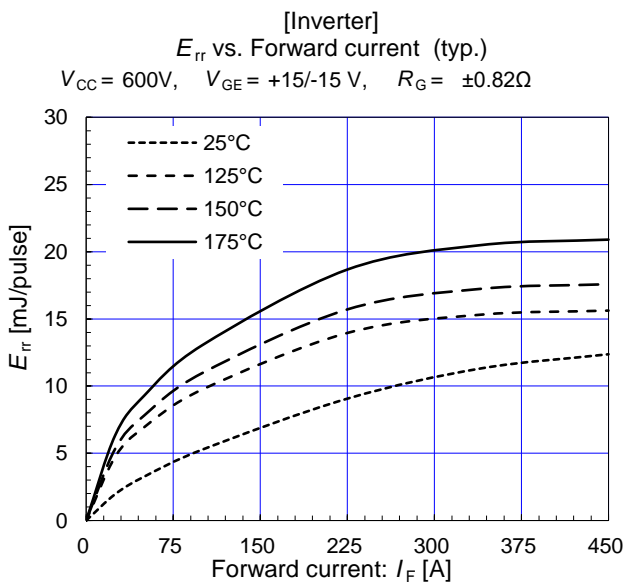
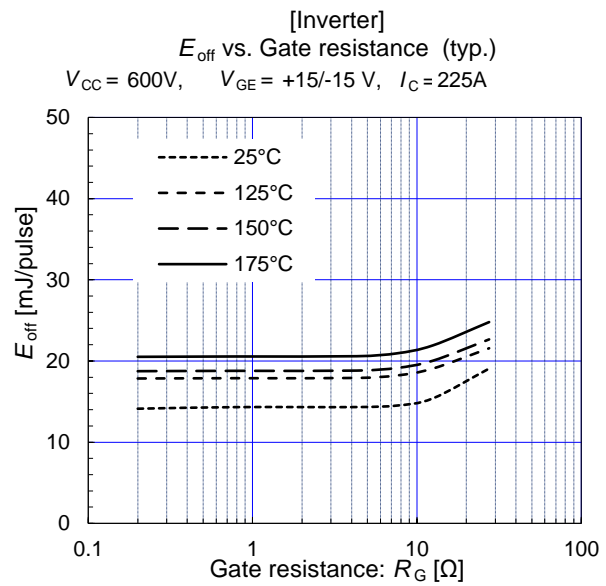
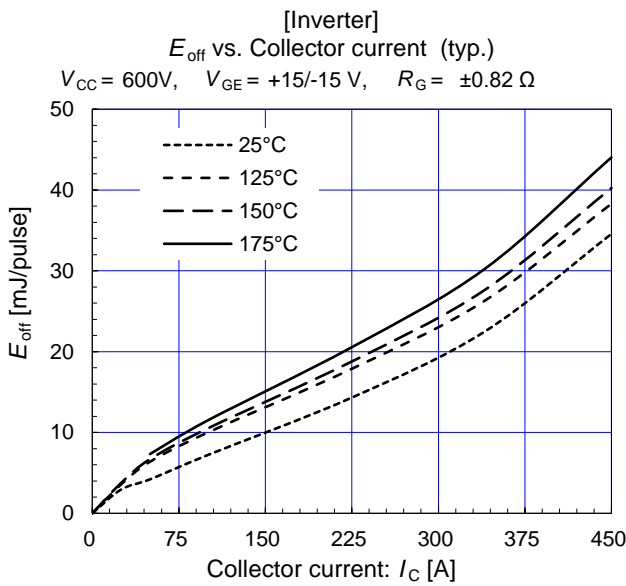
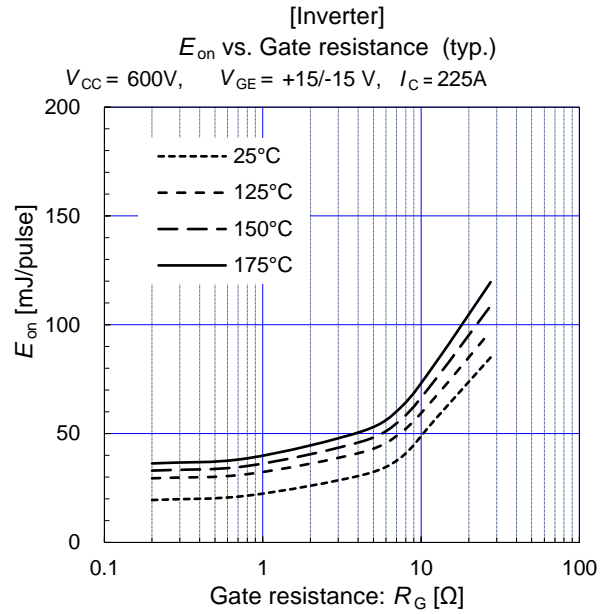
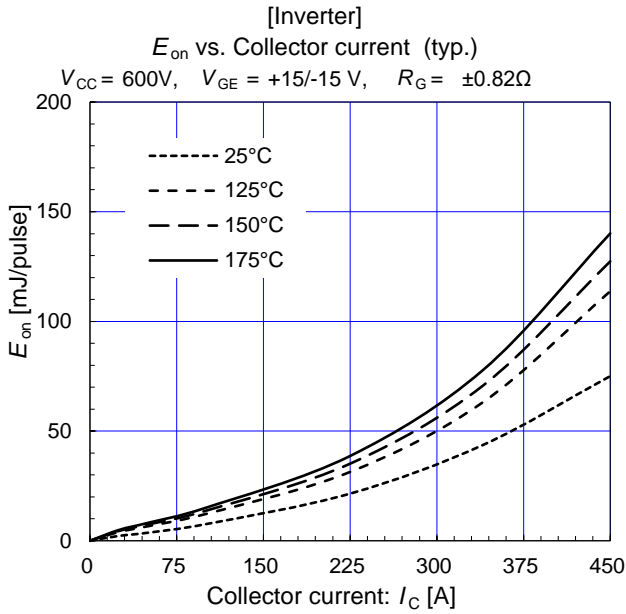
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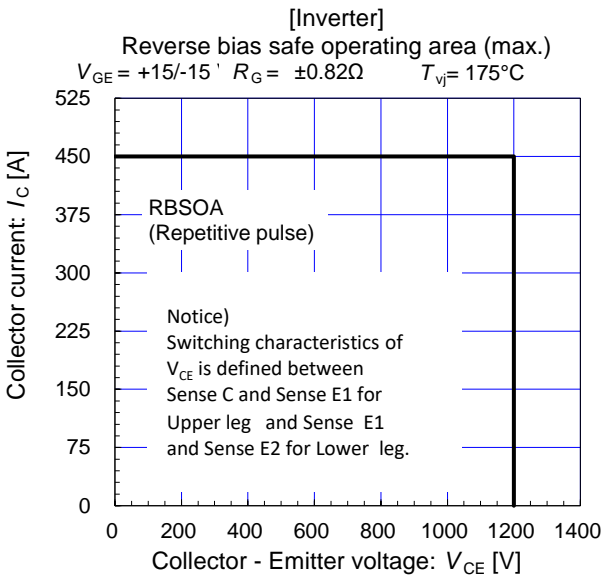
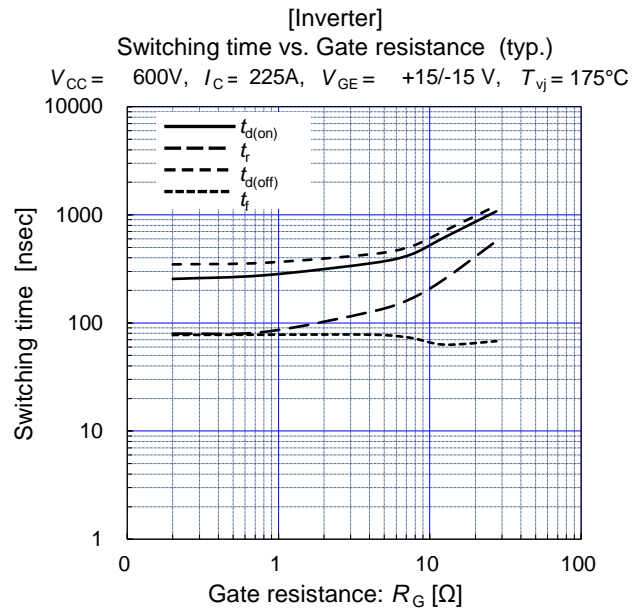
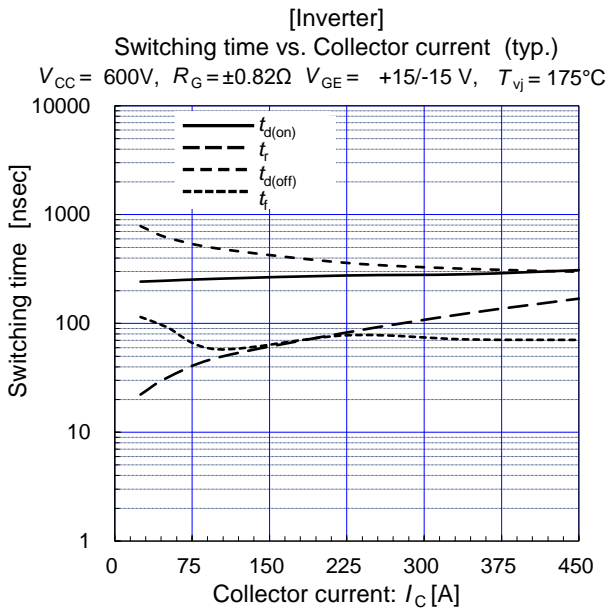
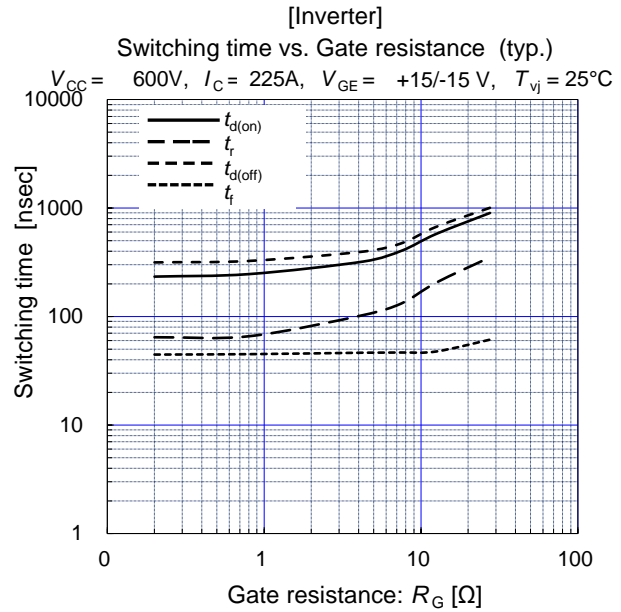
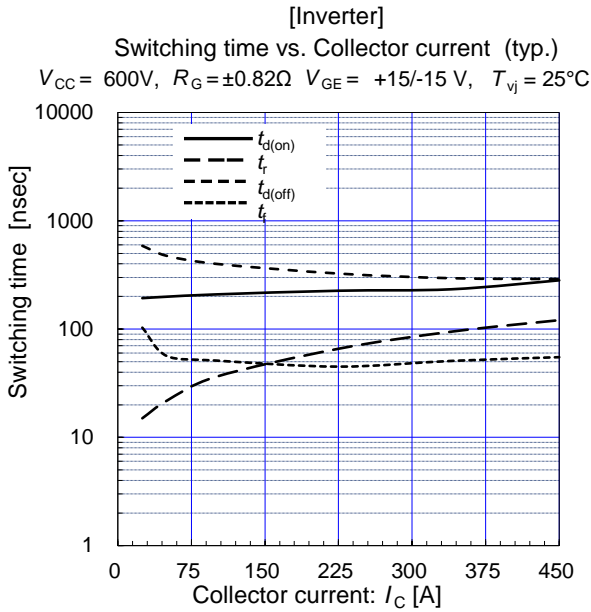
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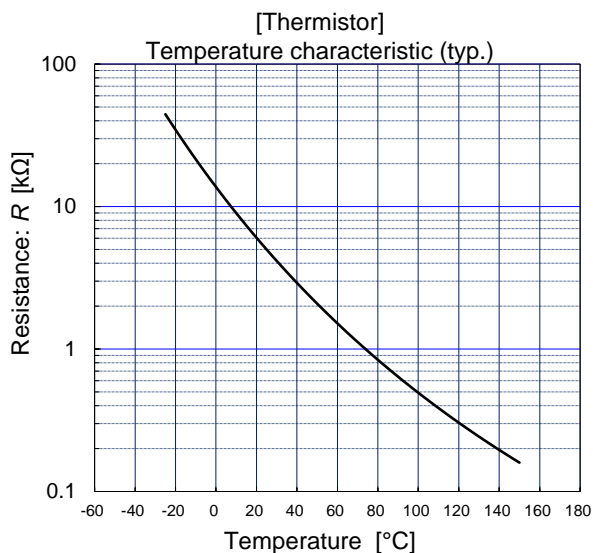
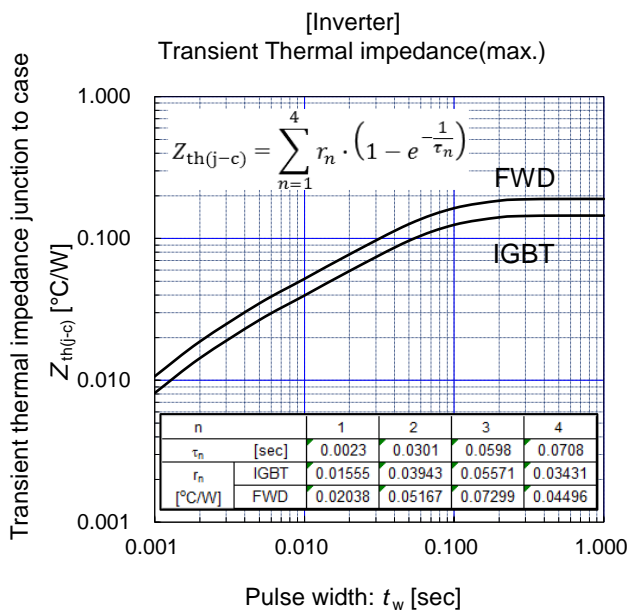
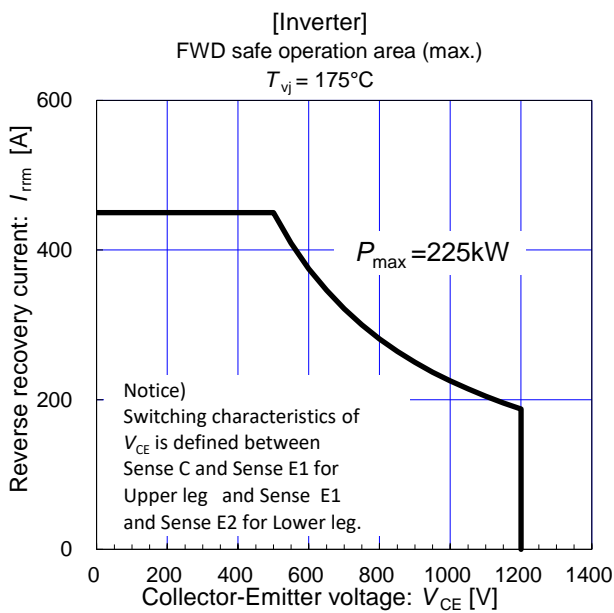
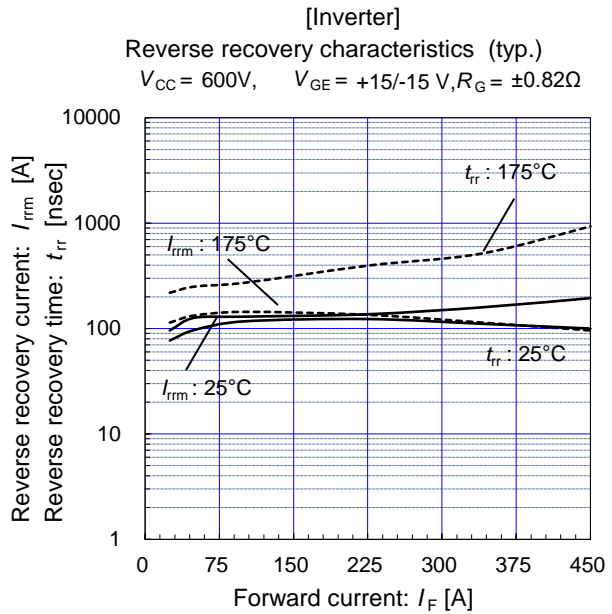
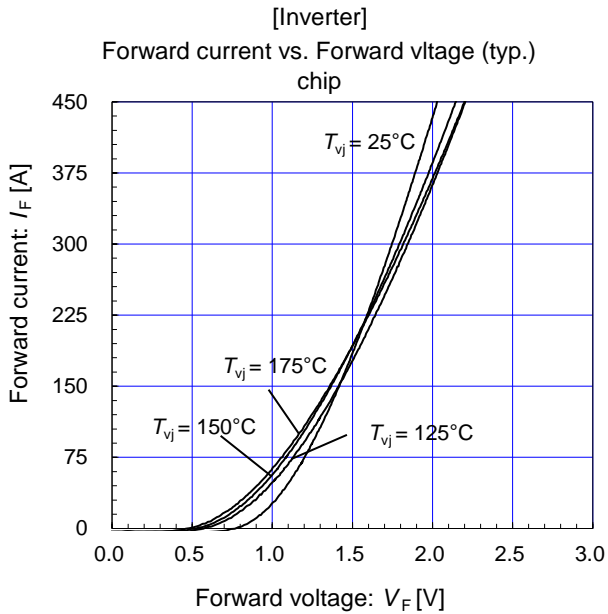
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